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December 2014

FDZ197PZ

P-Channel 1.5 V Specified PowerTrench® Thin WL-CSP MOSFET
-20 V, -3.8 A, 64 mΩ

Features

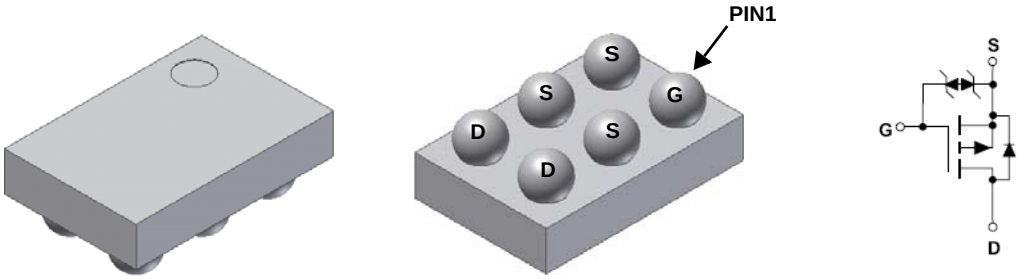
- Max $r_{DS(on)}$ = 64 mΩ at V_{GS} = -4.5 V, I_D = -2.0 A
- Max $r_{DS(on)}$ = 71 mΩ at V_{GS} = -2.5 V, I_D = -2.0 A
- Max $r_{DS(on)}$ = 79 mΩ at V_{GS} = -1.8 V, I_D = -1.0 A
- Max $r_{DS(on)}$ = 95 mΩ at V_{GS} = -1.5 V, I_D = -1.0 A
- Occupies only 1.5 mm^2 of PCB area.Less than 50% of the area of 2 x 2 BGA
- Ultra-thin package: less than 0.65 mm height when mounted to PCB
- HBM ESD protection level > 4400V (Note3)
- RoHS Compliant

General Description

Designed on Fairchild's advanced 1.5 V PowerTrench® process with state of the art "fine pitch" WLCSP packaging process, the FDZ197PZ minimizes both PCB space and $r_{DS(on)}$. This advanced WLCSP MOSFET embodies a breakthrough in packaging technology which enables the device to combine excellent thermal transfer characteristics, ultra-low profile packaging, low gate charge, and low $r_{DS(on)}$.

Applications

- Battery management
- Load switch
- Battery protection



TOP BOTTOM

WL-CSP 1x1.5 Thin

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
V_{DS}	Drain to Source Voltage			-20	V
V_{GS}	Gate to Source Voltage			±8	V
I_D	-Continuous	T_A = 25°C	(Note 1a)	-3.8	A
	-Pulsed			-15	
P_D	Power Dissipation	T_A = 25°C	(Note 1a)	1.9	W
	Power Dissipation	T_A = 25°C	(Note 1b)	0.9	
T_J, T_{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	65	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	133	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
7	FDZ197PZ	WL-CSP 1x1.5 Thin	7 ”	8 mm	5000 units

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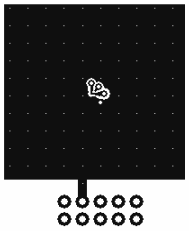
Electrical Characteristics T_J = 25 °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
BV_{DSS}	Drain to Source Breakdown Voltage	I_D = -250 μA, V_{GS} = 0 V	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = -250 μA, referenced to 25 °C		-10		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = -16 V, V_{GS} = 0 V			-1	μA
I_{GSS}	Gate to Source Leakage Current	V_{GS} = ±8 V, V_{DS} = 0 V			±10	μA
On Characteristics						
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = -250 μA	-0.4	-0.5	-1.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = -250 μA, referenced to 25 °C		2.7		mV/°C
$r_{DS(on)}$	Static Drain to Source On Resistance	V_{GS} = -4.5 V, I_D = -2.0 A		46	64	mΩ
		V_{GS} = -2.5 V, I_D = -2.0 A		53	71	
		V_{GS} = -1.8 V, I_D = -1.0 A		59	79	
		V_{GS} = -1.5 V, I_D = -1.0 A		68	95	
		V_{GS} = -4.5 V, I_D = -2.0 A, T_J =125 °C		54	84	
g_{FS}	Forward Transconductance	V_{DD} = -5 V, I_D = -3.8 A		21		S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = -10 V, V_{GS} = 0 V, f = 1 MHz		1180	1570	pF
C_{oss}	Output Capacitance			190	255	pF
C_{rss}	Reverse Transfer Capacitance			160	225	pF
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = -10 V, I_D = -3.8 A, V_{GS} = -4.5 V, R_{GEN} = 6 Ω		5.8	12	ns
t_r	Rise Time			5.9	12	ns
$t_{d(off)}$	Turn-Off Delay Time			311	498	ns
t_f	Fall Time			280	448	ns
Q_g	Total Gate Charge	V_{GS} = 0V to -4.5V, V_{DD} = -10 V, I_D = -3.8 A		18	25	nC
Q_{gs}	Gate to Source Charge			1.5		nC
Q_{gd}	Gate to Drain “Miller” Charge			4.7		nC
Drain-Source Diode Characteristics						
V_{SD}	Source to Drain Diode Forward Voltage	V_{GS} = 0 V, I_S = -1.1 A (Note 2)		-0.6	-1.2	V
t_{rr}	Reverse Recovery Time	I_F = -3.8 A, di/dt = 100 A/μs		194	310	ns
Q_{rr}	Reverse Recovery Charge			344	550	nC

Notes:

1. $R_{\theta JA}$ is determined with the device mounted on a 1 in^2 pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



a. 65 °C/W when mounted on a 1 in^2 pad of 2 oz copper.

b. 133 °C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300μs, Duty cycle < 2.0%.

3. The diode connected between the gate and source serves only as protection ESD. No gate overvoltage rating is implied.

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Typical Characteristics T_J = 25 °C unless otherwise noted

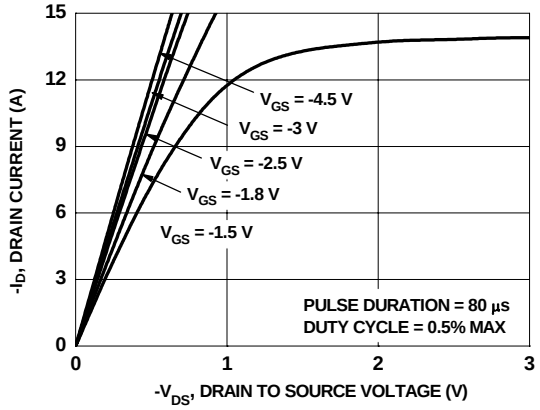

Figure 1. On-Region Characteristics

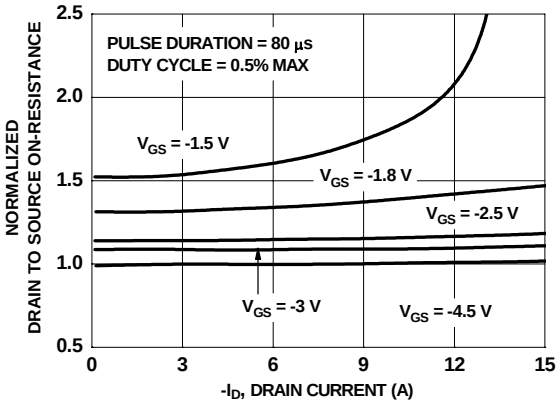

Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

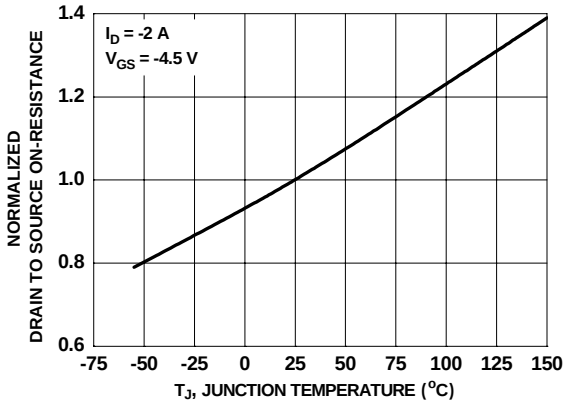

Figure 3. Normalized On-Resistance vs Junction Temperature

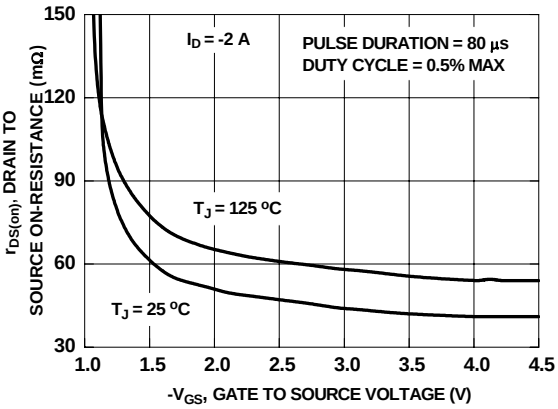

Figure 4. On-Resistance vs Gate to Source Voltage

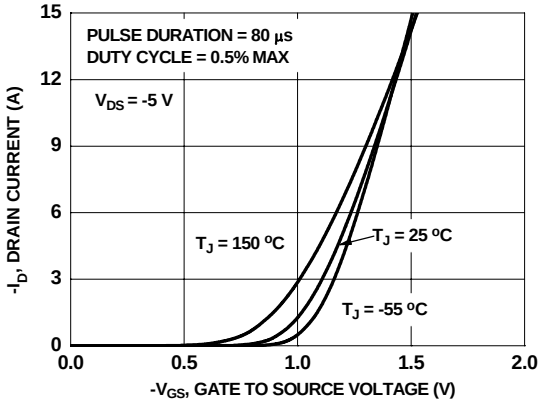

Figure 5. Transfer Characteristics

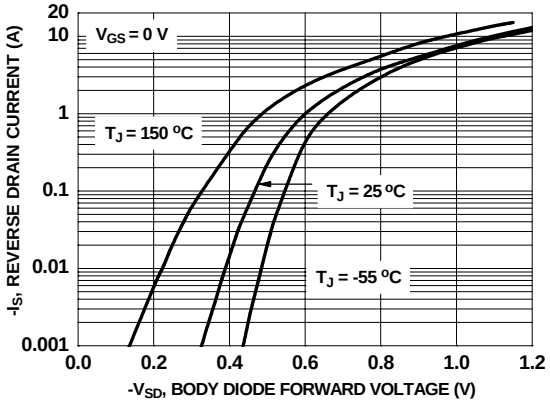

Figure 6. Source to Drain Diode Forward Voltage vs Source Current

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Typical Characteristics T_J = 25 °C unless otherwise noted

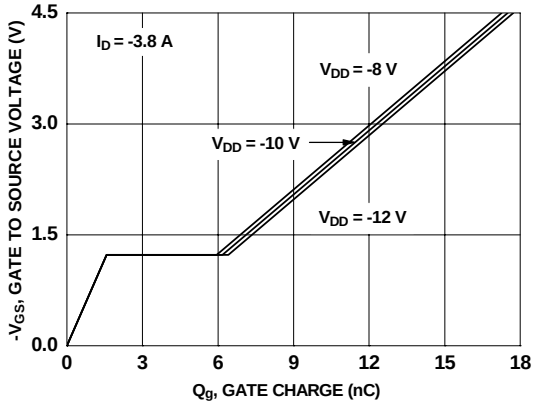

Figure 7. Gate Charge Characteristics

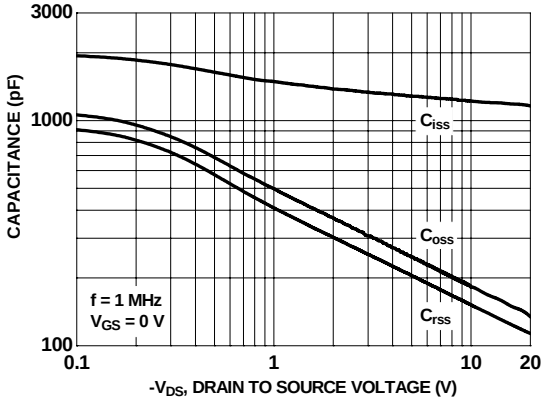

Figure 8. Capacitance vs Drain to Source Voltage

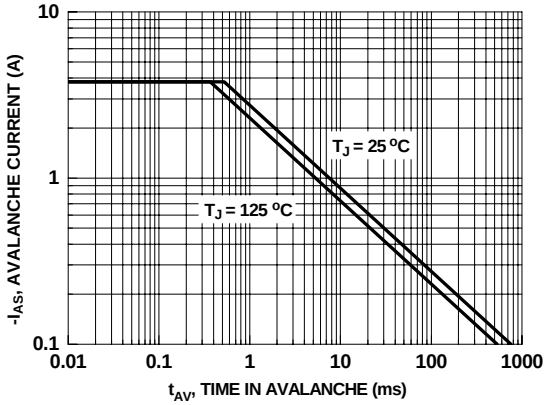

Figure 9. Unclamped Inductive Switching Capability

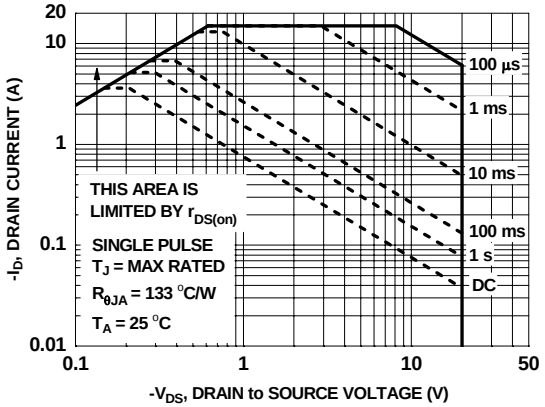

Figure 10. Forward Bias Safe Operating Area

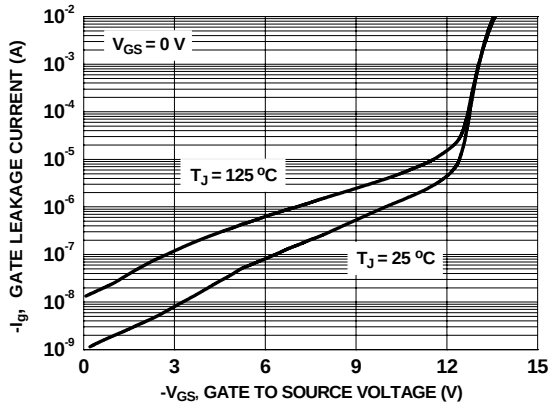

Figure 11. Gate Leakage Current vs Gate to Source Voltage

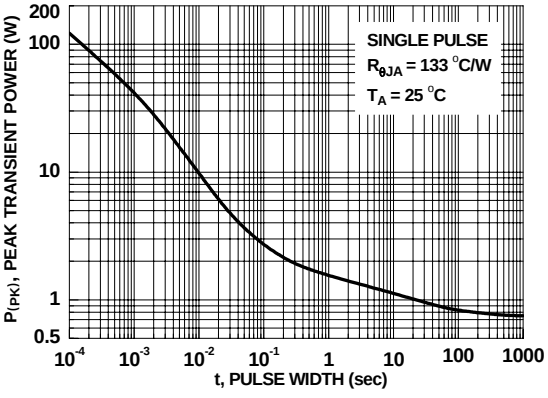

Figure 12. Single Pulse Maximum Power Dissipation

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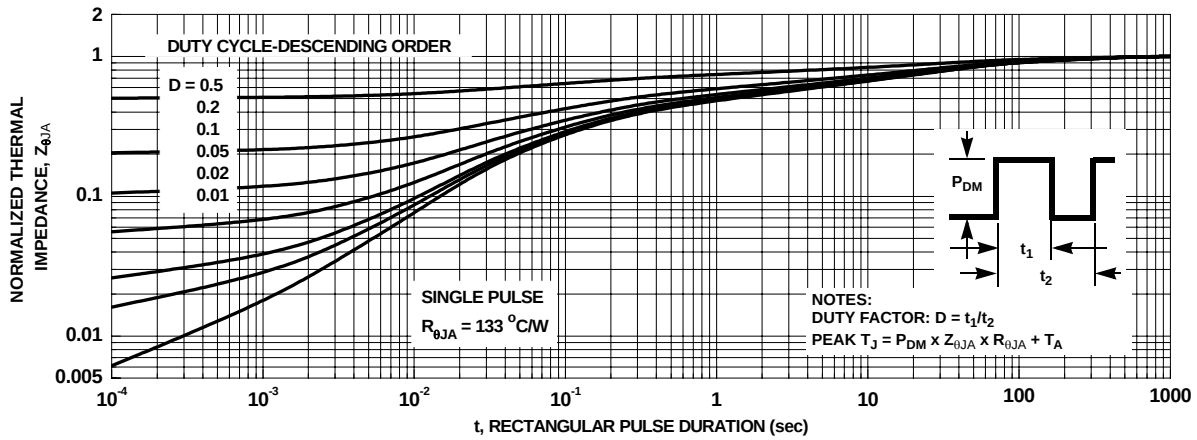
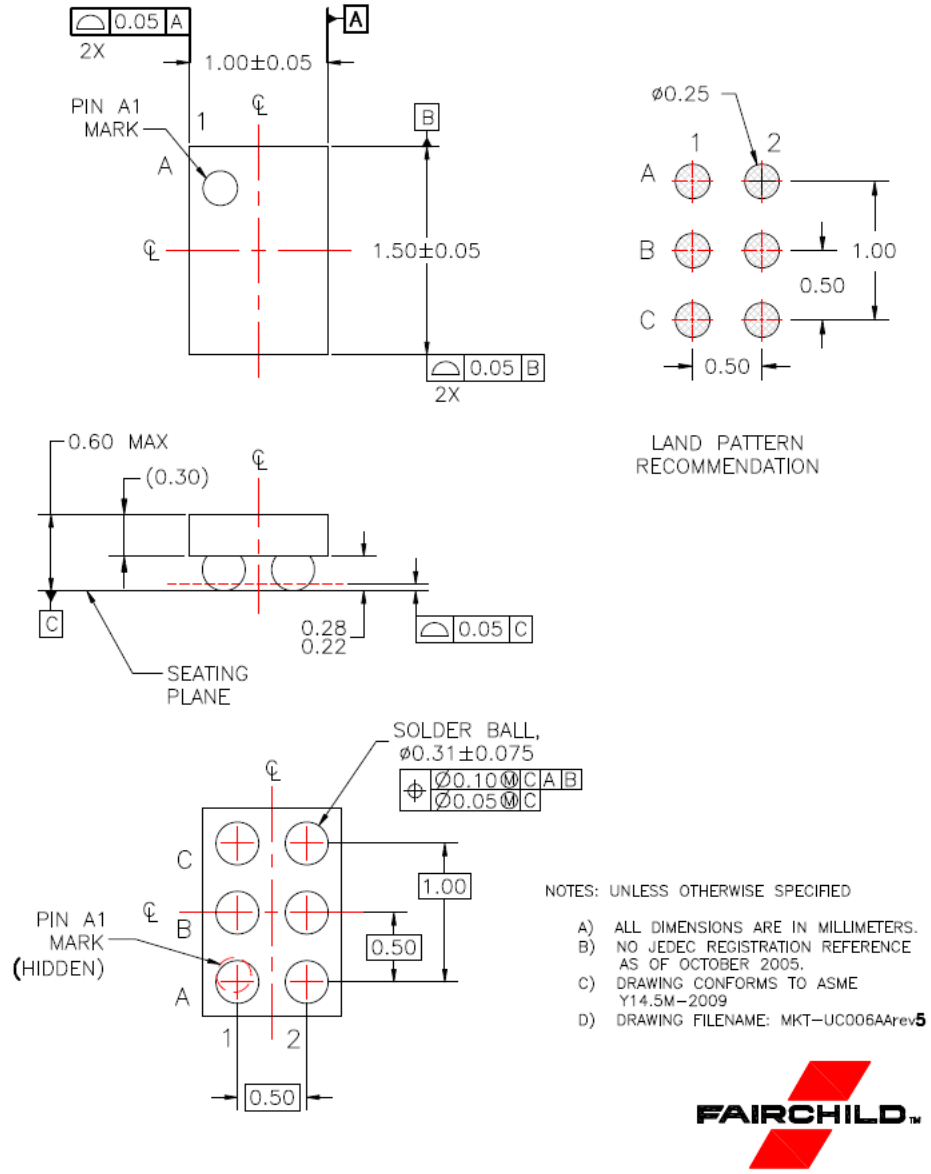


Figure 13. Transient Thermal Response Curve

Dimensional Outline and Pad Layout



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B) NO JEDEC REGISTRATION REFERENCE AS OF OCTOBER 2005.
C) DRAWING CONFORMS TO ASME Y14.5M–2009
D) DRAWING FILENAME: MKT–UC006AArev5

Pin Definations:

Gate	Drain	Source
A1	C1, C2	A2, B1, B2

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